

# PESD5V0F1BRSF

Extremely low capacitance bidirectional ESD protection diodeRev. 1 — 13 February 2013Product data sheet

#### **Product profile** 1.

### **1.1 General description**

Extremely low capacitance bidirectional ElectroStatic Discharge (ESD) protection diode in a DSN0603-2 (SOD962) leadless ultra small Surface-Mounted Device (SMD) package designed to protect one signal line from the damage caused by ESD and other transients.

### 1.2 Features and benefits

- Bidirectional ESD protection of one line
- Extremely low diode capacitance C<sub>d</sub> = 0.25 pF
- Minimized capacitance variation over voltage
- ESD protection up to ±10 kV according to IEC 61000-4-2
- Ultra small SMD package

### 1.3 Applications

- Cellular handsets and accessories
- Portable electronics
- Communication systems
- Computers and peripherals

### 1.4 Quick reference data

#### Table 1. Quick reference data

 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>RWM</sub>	reverse standoff voltage		-	-	5	V
C <sub>d</sub>	diode capacitance	$f = 1 \text{ MHz}; V_R = 0 \text{ V}$	0.20	0.25	0.30	pF

## 2. Pinning information

Table 2.	Pinning		
Pin	Description	Simplified outline	Graphic symbol
1	cathode (diode 1)		
2	cathode (diode 2)	1 2	1 2 sym045
		Transparent top view	



## 3. Ordering information

Table 3. Ordering	g information		
Type number	Package		
	Name	Description	Version
PESD5V0F1BRSF	DSN0603-2	leadless ultra small package; 2 terminals; body $0.6 \times 0.3 \times 0.3$ mm	SOD962

## 4. Marking

Table 4.	Marking codes		
Type num	nber	Marking code	
PESD5V0	F1BRSF	F	

## 5. Limiting values

#### Table 5. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

Symbol	Parameter	Conditions	Min	Мах	Unit
P <sub>PPM</sub>	rated peak pulse power	t <sub>p</sub> = 8/20 μs	<u>[1]</u> _	28	W
I <sub>PPM</sub>	rated peak pulse current	t <sub>p</sub> = 8/20 μs	<u>[1]</u> _	2.2	А
T <sub>j</sub>	junction temperature		-	150	°C
T <sub>amb</sub>	ambient temperature		-55	+150	°C
T <sub>stg</sub>	storage temperature		-65	+150	°C

[1] Non-repetitive current pulse 8/20 µs exponentially decaying waveform according to IEC61000-4-5.

#### Table 6. ESD maximum ratings

Symbol	Parameter	Conditions	Min	Max	Unit
V <sub>ESD</sub> electrostatic discharge voltage		IEC 61000-4-2 (contact discharge)	<u>[1]</u> _	10	kV
	IEC 61000-4-2 (air discharge)	<u>[1]</u> _	15	kV	
		MIL-STD-883 (human body model)	-	10	kV

[1] Device stressed with ten non-repetitive ESD pulses.

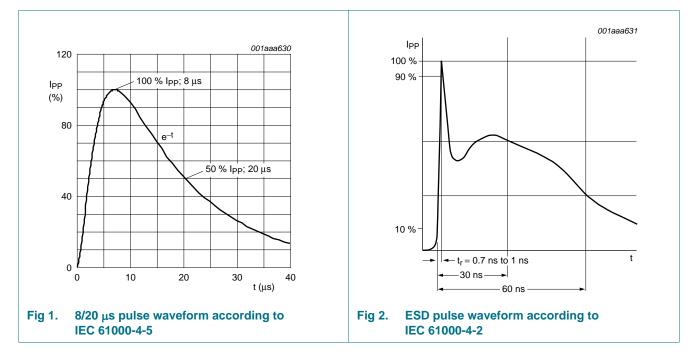
#### Table 7. ESD standards compliance

Standard	Conditions
IEC 61000-4-2, level 4 (ESD)	> 15 kV (air); > 8 kV (contact)
MIL-STD-883; class 3B (human body model)	> 8 kV

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## 6. Characteristics

#### Table 8.Characteristics

 $T_{amb} = 25 \ ^{\circ}C$  unless otherwise specified.

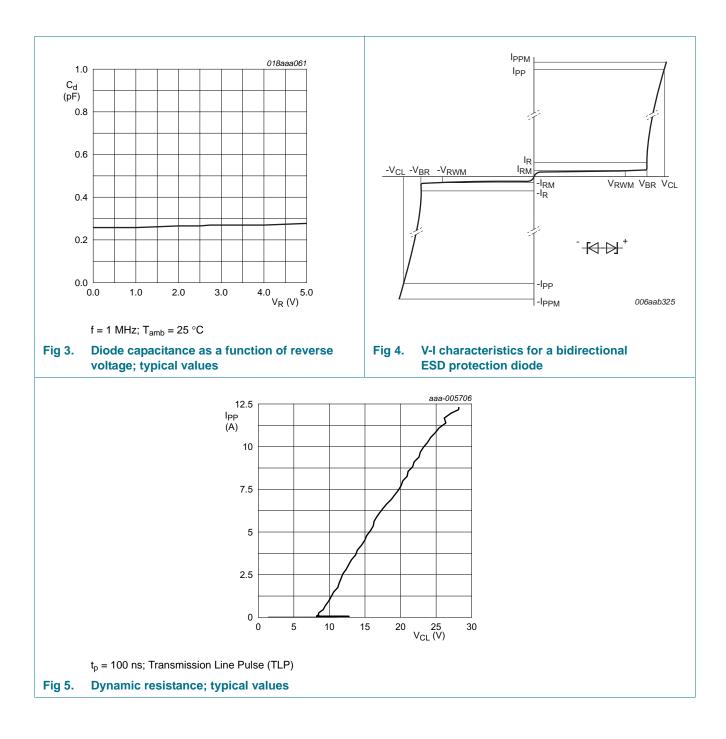
Symbol	Parameter	Conditions	Min	Тур	Max	Unit
V <sub>RWM</sub>	reverse standoff voltage		-	-	5	V
I <sub>RM</sub>	reverse leakage current	$V_{RWM} = 5 V$	-	1	100	nA
V <sub>CL</sub>	clamping voltage	I <sub>PP</sub> = 0.5 A	<u>[1]</u> _	-	10	V
		I <sub>PPM</sub> = 2.2 A	<u>[1]</u> _	-	12.8	V
V <sub>BR</sub>	breakdown voltage	I <sub>R</sub> = 1 mA	6	-	10	V
C <sub>d</sub>	diode capacitance	$f = 1 MHz; V_R = 0 V$	0.20	0.25	0.30	pF
<b>r</b> <sub>dyn</sub>	dynamic resistance	I <sub>R</sub> = 10 A	[2] _	1.3	-	Ω

[1] Non-repetitive current pulse 8/20 µs exponential decay waveform according to IEC 61000-4-5.

[2] Non-repetitive current pulse, Transmission Line Pulse (TLP)  $t_p$  = 100 ns; square pulse; ANS/IESD STM5.1-2008.

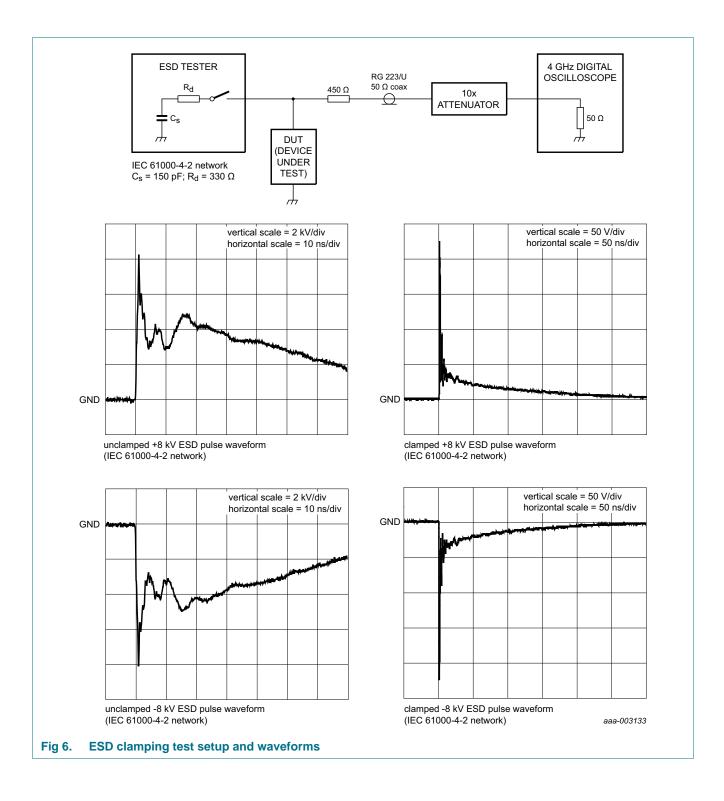
# PESD5V0F1BRSF

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# PESD5V0F1BRSF

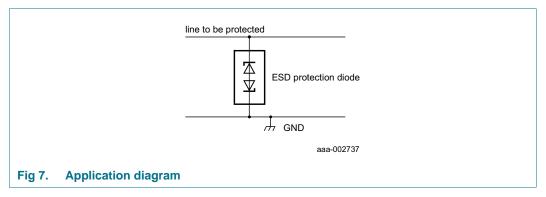
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## 7. Application information

The PESD5V0F1BRSF is designed for the protection of one data or signal line from surge pulses and ESD damage. The device is suitable on lines where the signal polarities are both, positive and negative with respect to ground. It provides protection against surges with up to 28 W per line.



#### Circuit board layout and protection device placement

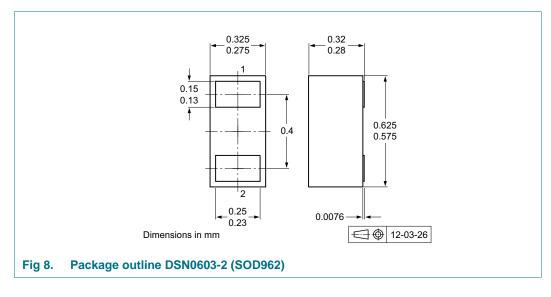
Circuit board layout is critical for the suppression of ESD, Electrical Fast Transient (EFT) and surge transients. The following guidelines are recommended:

- 1. Place the device as close to the input terminal or connector as possible.
- 2. Minimize the path length between the device and the protected line.
- 3. Keep parallel signal paths to a minimum.
- 4. Avoid running protected conductors in parallel with unprotected conductors.
- 5. Minimize all Printed-Circuit Board (PCB) conductive loops including power and ground loops.
- 6. Minimize the length of the transient return path to ground.
- 7. Avoid using shared transient return paths to a common ground point.
- 8. Use ground planes whenever possible. For multilayer PCBs, use ground vias.

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## 8. Package outline



## 9. Packing information

#### Table 9. Packing methods

The indicated -xxx are the last three digits of the 12NC ordering code.[1]

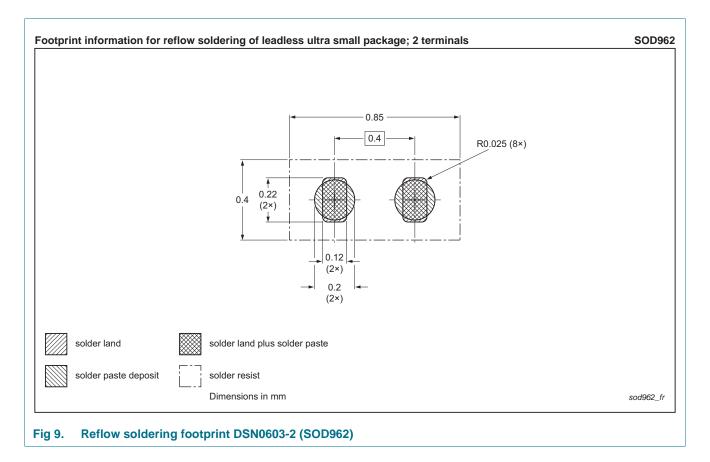
Type number	Package	Description	Packing quantity
			9000
PESD5V0F1BRSF	DSN0603-2 (SOD962)	2 mm pitch, 8 mm tape and reel	-315

[1] For further information and the availability of packing methods, see <u>Section 13</u>.

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## **10. Soldering**



## **11. Revision history**

Table 10. Revision history					
Document ID	Release date	Data sheet status	Change notice	Supersedes	
PESD5V0F1BRSF v.1	20130213	Product data sheet	-	-	

## **12. Legal information**

#### 12.1 Data sheet status

Document status[1][2]	Product status <sup>[3]</sup>	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
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